

Excellent Integrated System Limited

Stocking Distributor

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ON Semiconductor NRVBS3100T3G

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>



Distributor of ON Semiconductor: Excellent Integrated System Limited Datasheet of NRVBS3100T3G - DIODE SCHOTTKY 100V 3A SMC Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

MBRS3100T3G, NRVBS3100T3G

Surface Mount Schottky Power Rectifier

This device employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes, in surface mount applications where compact size and weight are critical to the system.

Features

- Small Compact Surface Mountable Package with J-Bend Leads
- · Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- Excellent Ability to Withstand Reverse Avalanche Energy Transients
- · Guard-Ring for Stress Protection
- AEC-Q101 Qualified and PPAP Capable
- NRVB Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- All Packages are Pb-Free*
- **Mechanical Characteristics**
- Case: Epoxy, Molded
- Weight: 217 mg (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- · Polarity: Notch in Plastic Body Indicates Cathode Lead
- ESD Ratings:
 - Machine Model = C
 - ◆ Human Body Model = 3B



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http://onsemi.com

SCHOTTKY BARRIER RECTIFIERS 3.0 AMPERES, 100 VOLTS



SMC CASE 403

MARKING DIAGRAM



B310 = Specific Device Code А

- = Assembly Location
- = Year

Y

ww

- = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MBRS3100T3G	SMC (Pb-Free)	2,500 / Tape & Reel
NRVBS3100T3G	SMC (Pb-Free)	2,500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



MBRS3100T3G, NRVBS3100T3G

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	V
Average Rectified Forward Current (At Rated V _R , T _L = 100°C)	I _{F(AV)}	3.0	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	130	A
Operating Junction Temperature Range (Note 1)	TJ	– 65 to +175	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Lead	$R_{\theta JL}$	11	°C/W

ELECTRICAL CHARACTERISTICS

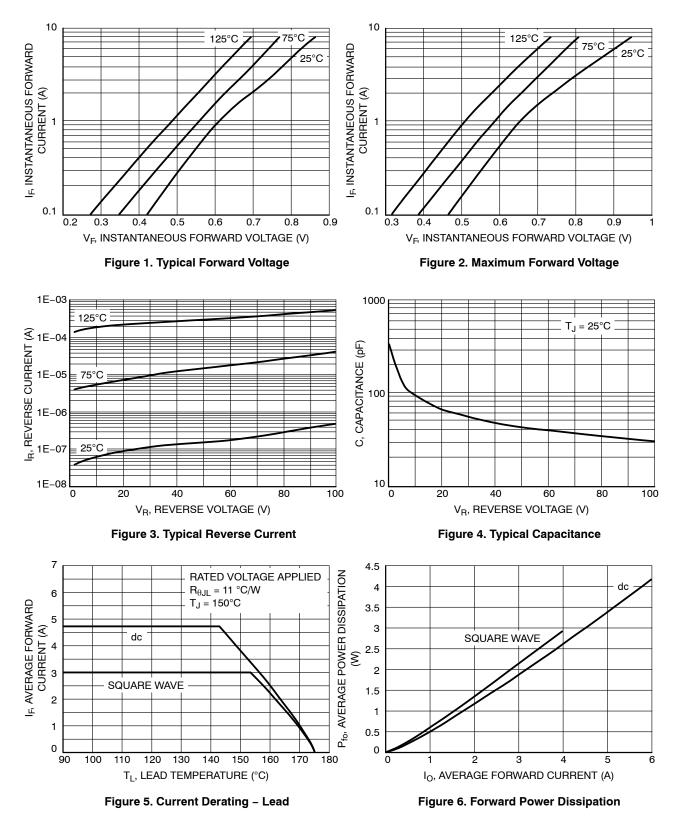
Characteristic	Symbol	Value	Unit
$\begin{array}{l} \text{Maximum Instantaneous Forward Voltage (Note 2)} \\ (i_F = 3.0 \text{ A}, \text{T}_\text{J} = 25^\circ\text{C}) \\ (i_F = 6.0 \text{ A}, \text{T}_\text{J} = 25^\circ\text{C}) \\ (i_F = 3.0 \text{ A}, \text{T}_\text{J} = 125^\circ\text{C}) \\ (i_F = 6.0 \text{ A}, \text{T}_\text{J} = 125^\circ\text{C}) \end{array}$	V _F	0.79 0.90 0.62 0.70	V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_J = 25^{\circ}$ C) (Rated dc Voltage, $T_J = 125^{\circ}$ C)	i _R	0.05 5.0	mA

2. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.



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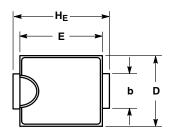
MBRS3100T3G, NRVBS3100T3G





MBRS3100T3G, NRVBS3100T3G

PACKAGE DIMENSIONS

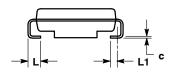


SMC CASE 403-03 ISSUE E

> NOTES DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
> CONTROLLING DIMENSION: INCH.
> D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.

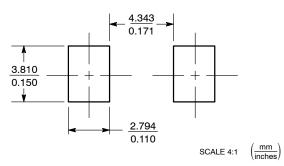
403-01 THRU -02 OBSOLETE, NEW STANDARD 403-03.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
A	1.90	2.13	2.41	0.075	0.084	0.095
A1	0.05	0.10	0.15	0.002	0.004	0.006
b	2.92	3.00	3.07	0.115	0.118	0.121
С	0.15	0.23	0.30	0.006	0.009	0.012
D	5.59	5.84	6.10	0.220	0.230	0.240
E	6.60	6.86	7.11	0.260	0.270	0.280
HE	7.75	7.94	8.13	0.305	0.313	0.320
L	0.76	1.02	1.27	0.030	0.040	0.050
L1		0.51 REF		0.020 REF		





SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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